

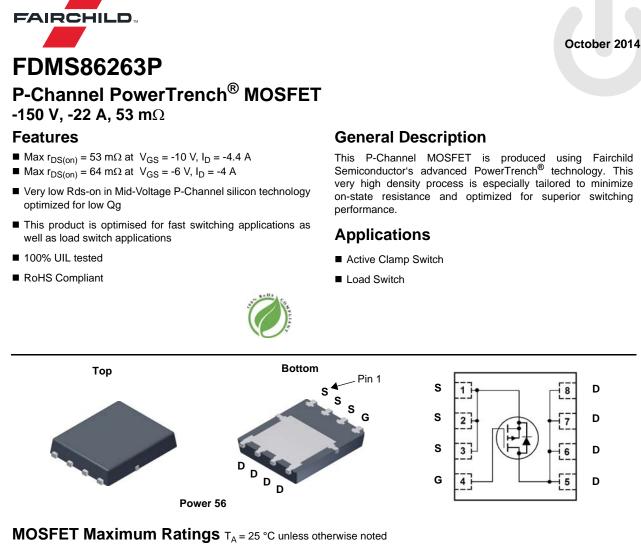
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Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			-150	V	
V _{GS}	Gate to Source Voltage			±25	V	
	Drain Current -Continuous	T _C = 25 °C		-22		
I _D	-Continuous	T _A = 25 °C	(Note 1a)	-4.4	A	
	-Pulsed			-70		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	384	mJ	
D	Power Dissipation	T _C = 25 °C		104		
P _D	Power Dissipation	T _A = 25 °C	(Note 1a)	2.5		
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C		

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.2	°C/W]
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1a) 50	C/VV	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS86263P	FDMS86263P	Power 56	13 "	12 mm	3000 units

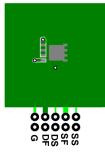
FDMS86263P P-Channel PowerTrench[®] MOSFET

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DMS8
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wer ⁻
Trench
[®] MOS
SFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = -250 μA, V _{GS} = 0 V				V
ΔBV_{DSS} ΔT_{J}	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, referenced to 25 °C		-116		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -120 V, V _{GS} = 0 V			-1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	cteristics			4		
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = -250 μA	-2	-2.9	-4	V
$\Delta V_{GS(th)}$ ΔT_J	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, referenced to 25 °C		7		mV/°C
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = -10 V, I _D = -4.4 A		42	53	
		$V_{GS} = -6 V, I_D = -4 A$		45	64	mΩ
		V_{GS} = -10 V, I_{D} = -4.4 A, T_{J} = 125 °C		71	94	
9 _{FS}	Forward Transconductance	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -4.4 \text{ A}$		19		S
C	Input Capacitance	– V _{DS} = -75 V, V _{GS} = 0 V,		2935 238	3905 315	pF pF
C _{oss}	Output Capacitance	─ V _{DS} = -75 V, V _{GS} = 0 V, f = 1 MHz		238	315	pF
C _{rss}	Reverse Transfer Capacitance			11	20	pF
R _g	Gate Resistance		0.1	2.7	5.4	Ω
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			17	31	ns
t _r	Rise Time	V _{DD} = -75 V, I _D = -4.4 A,		10	21	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = -10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		37	59	ns
t _f	Fall Time			14	25	ns
Qg	Total Gate Charge	V _{GS} = 0 V to -10 V		45	63	nC
Qg	Total Gate Charge	$V_{GS} = 0 \text{ V to } -6 \text{ V} \text{ V}_{DD} = -75 \text{ V},$		29	40	nC
Q _{gs}	Gate to Source Charge	I _D = -4.4 A		11.3		nC
Q _{gd}	Gate to Drain "Miller" Charge			8.9		nC
Drain-Sou	urce Diode Characteristics					
		$V_{GS} = 0 V, I_S = -4.4 A$ (Note 2)		-0.79	-1.3	
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = -2 A$ (Note 2)		-0.75	-1.2	V
t _{rr}	Reverse Recovery Time	L = 4.4.4 di/dt = 400.4/vc		91	146	ns
	Reverse Recovery Charge	– I _F = -4.4 A, di/dt = 100 A/μs		287	460	nC

Notes:

1. R_{0JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



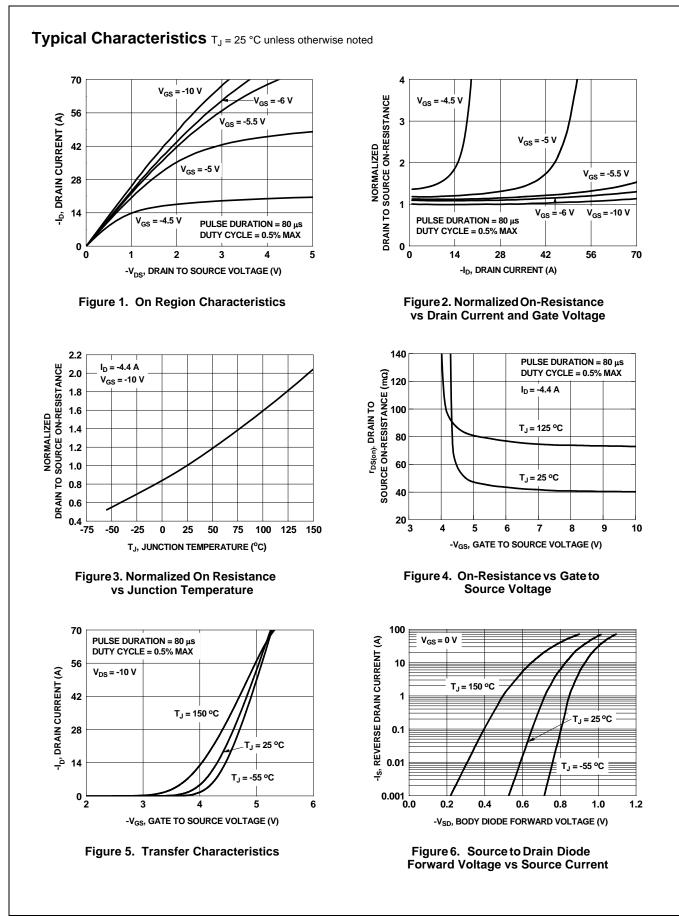
a) 50 °C/W when mounted on a 1 in² pad of 2 oz copper

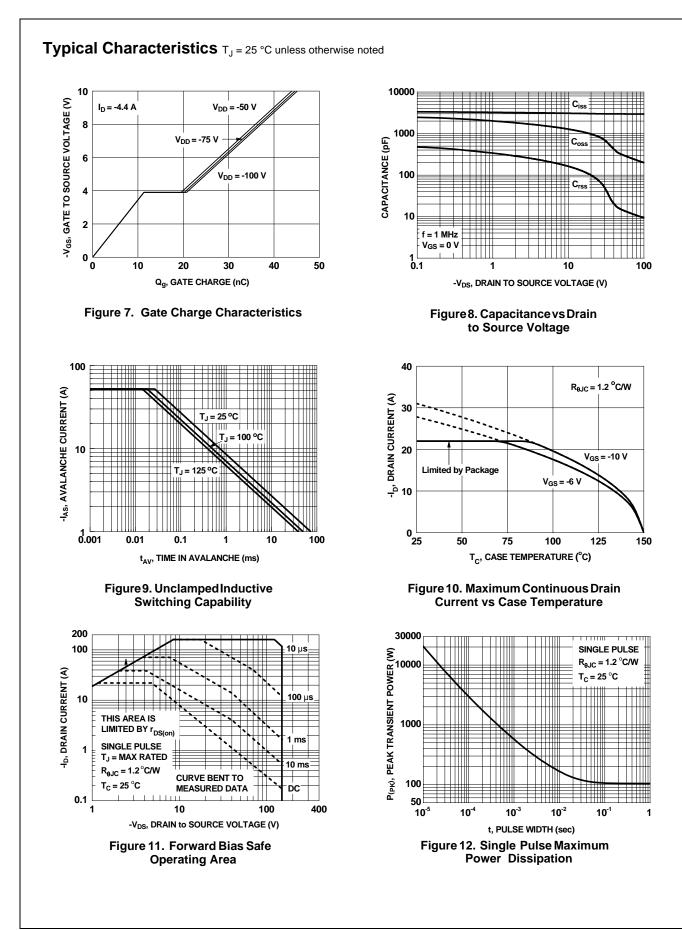


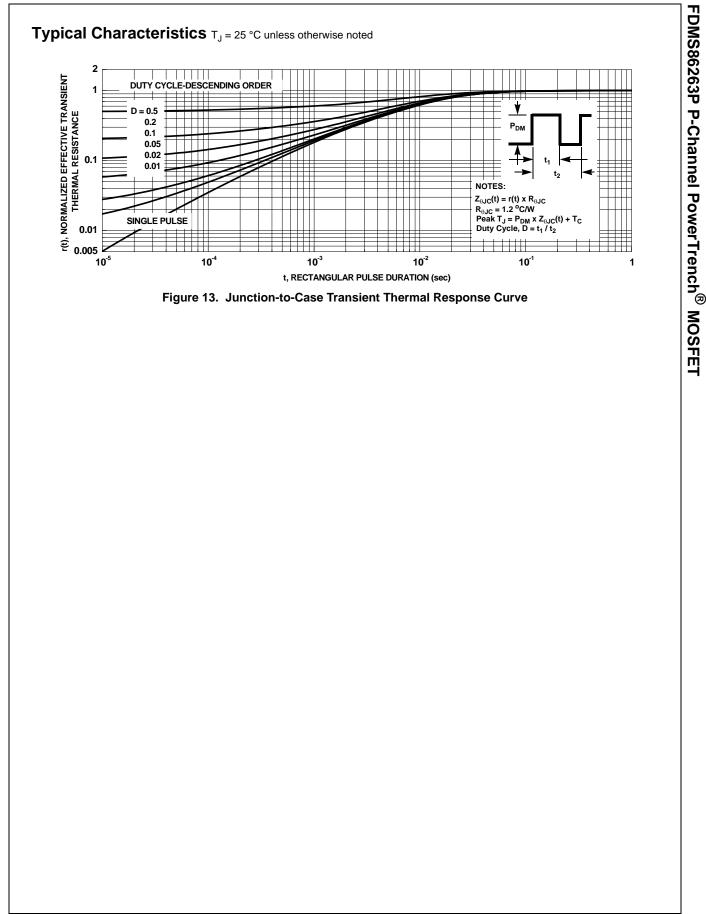
b) 125 °C/W when mounted on a minimum pad of 2 oz copper.

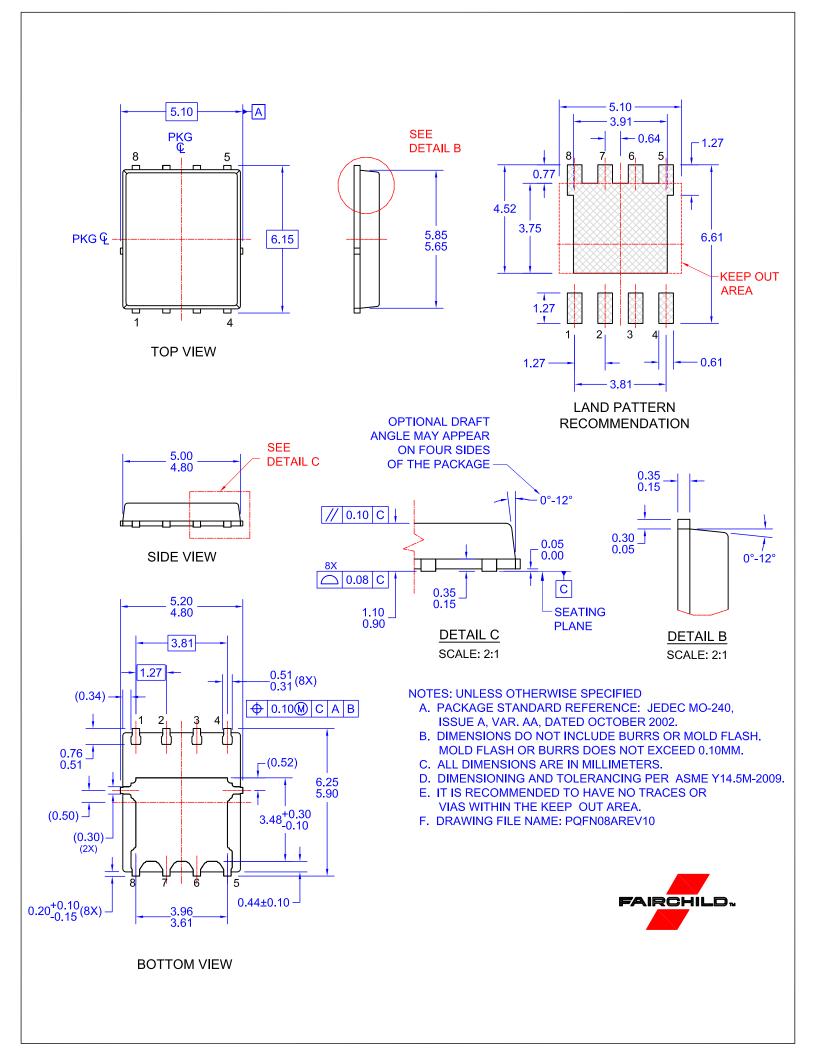
2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%.

3. Starting T_J = 25 °C; P-ch: L = 3 mH, I_{AS} = -16 A, V_{DD} = -150 V, V_{GS} = -10 V. 100% test at L = 0.1 mH, I_{AS} = -52 A.









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